NP0A456

Silicon PNP epitaxial planar type

For High speed switching

■ Features

- Suitable for high-density mounting and downsizing of the equipment
- Automatic insertion with the taping is possible

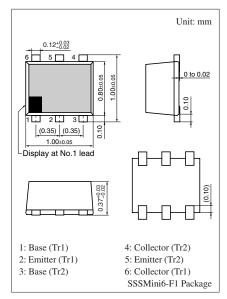
■ Basic Part Number

• 2SA2082 × 2

■ Absolute Maximum Ratings $T_a = 25$ °C

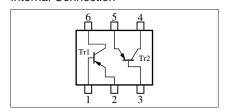
Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	-15	V	
Collector-emitter voltage (Base open)	V _{CEO}	-15	V	
Emitter-base voltage (Collector open)	V_{EBO}	-4	V	
Collector current	I_C	-50	mA	
Peak collector current	I_{CP}	-100	mA	
Total power dissipation *	P_{T}	125	mW	
Junction temperature	T_{j}	125	°C	
Storage temperature	T_{stg}	-55 to +125	°C	

Note) *: Measuring on substrate at 17 mm \times 10 mm \times 1 mm



Marking Symbol: 3E

Internal Connection



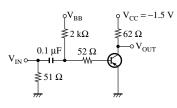
■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

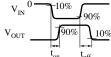
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = -8 \text{ V}, I_E = 0$			- 0.1	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = -3 \text{ V}, I_C = 0$			- 0.1	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = -1 \text{ V}, I_{C} = -10 \text{ mA}$	50		150	_
	h _{FE2}	$V_{CE} = -1 \text{ V}, I_{C} = -1 \text{ mA}$	30			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_C = -10 \text{ mA}, I_B = -1 \text{ mA}$		- 0.1	- 0.2	V
Transition frequency	f_T	$V_{CB} = -10 \text{ V}, I_E = 10 \text{ mA}, f = 200 \text{ MHz}$	800	1 500		MHz
Collector output capacitance	C _{ob}	$V_{CB} = -5 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		1		pF
(Common base, input open circuited)						
Turn-on time	t _{on}	Refer to the switching time measurement circuit		12		ns
Turn-off time	t _{off}			20		ns
Storage time	t _{stg}			19		ns

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Switching time measurement circuit

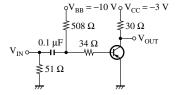


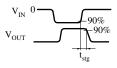




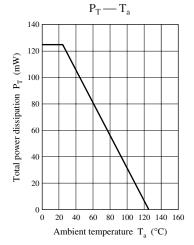
$$V_{IN} = -5.8 \text{ V}$$
 $V_{IN} = 9.8 \text{ V}$
 $V_{BB} = \text{Ground}$ $V_{BB} = -8.0 \text{ V}$

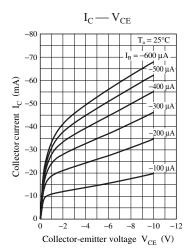


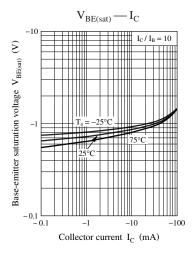


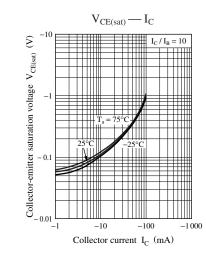


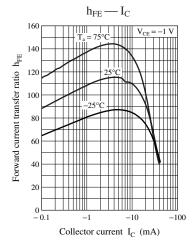


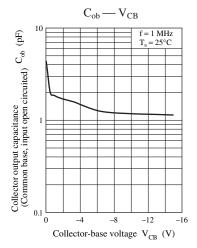












2 SJJ00269BED

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